

# 1 AMP MINIATURE BRIDGE RECTIFIERS

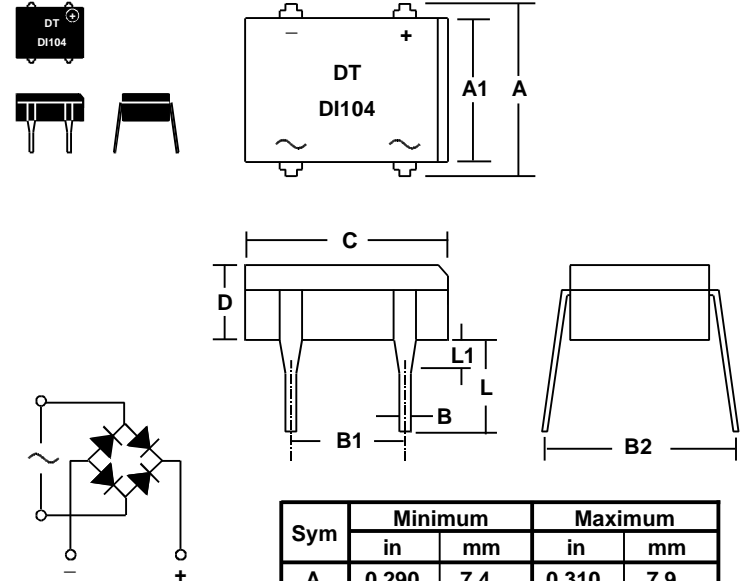
## FEATURES

- PRV Ratings from 50 to 1000 Volts
  - Surge overload rating to 50 Amps peak
  - Reliable low cost molded plastic construction
  - Ideal for printed circuit board applications
  - **UL RECOGNIZED - FILE #E124962**
- ## MECHANICAL DATA
- Case: Molded plastic, U/L Flammability Rating 94V-0
  - Terminals: Rectangular pins
  - Soldering: Per MIL-STD 202 Method 208 guaranteed
  - Polarity: Marked on case
  - Mounting Position: Any
  - Weight: 0.05 Ounces (1.3 Grams)

## MECHANICAL SPECIFICATION

ACTUAL SIZE OF THE DI PACKAGE

SERIES DI100 - DI110



| Sym | Minimum |      | Maximum |      |
|-----|---------|------|---------|------|
|     | in      | mm   | in      | mm   |
| A   | 0.290   | 7.4  | 0.310   | 7.9  |
| A1  | 0.245   | 6.2  | 0.255   | 6.5  |
| B   | 0.016   | 0.41 | 0.020   | 0.51 |
| B1  | 0.195   | 5.0  | 0.205   | 5.2  |
| B2  | 0.300   | 7.6  | 0.350   | 8.9  |
| C   | 0.355   | 9.3  | 0.365   | 9.3  |
| D   | 0.125   | 3.2  | 0.135   | 3.4  |
| L   | 0.155   | 3.9  | 0.165   | 4.3  |
| L1  | 0.060*  | 1.5* |         |      |

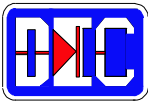
\* This dimension is "Typical".

## MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60Hz, resistive or inductive load.  
 For capacitive loads, derate current by 20%.

| PARAMETER (TEST CONDITIONS)   | SYMBOL                            | RATINGS     |       |       |       |       |       |       | UNITS |
|---|-----------------------------------|-------------|-------|-------|-------|-------|-------|-------|-------|
|   |                                   | DI100       | DI101 | DI102 | DI104 | DI106 | DI108 | DI110 |       |
| Series Number   |                                   |             |       |       |       |       |       |       |       |
| Maximum DC Blocking Voltage   | V <sub>RM</sub>                   | 50          | 100   | 200   | 400   | 600   | 800   | 1000  | VOLTS |
| Maximum RMS Voltage   | V <sub>RMS</sub>                  | 35          | 70    | 140   | 280   | 420   | 560   | 700   |       |
| Maximum Peak Recurrent Reverse Voltage  | V <sub>RRM</sub>                  | 50          | 100   | 200   | 400   | 600   | 800   | 1000  |       |
| Average Forward Rectified Current @ T <sub>A</sub> = 40 °C                          | I <sub>O</sub>                    | 1           |       |       |       |       |       |       | AMPS  |
| Peak Forward Surge Current (8.3ms single half sine wave superimposed on rated load) | I <sub>FSM</sub>                  | 50          |       |       |       |       |       |       |       |
| Maximum Forward Voltage (Per Diode) at 1 Amp DC                                     | V <sub>FM</sub>                   | 1.1         |       |       |       |       |       |       | VOLTS |
| Maximum Average DC Reverse Current @ T <sub>A</sub> = 25 °C                         | I <sub>RM</sub>                   | 5.0         |       |       |       |       |       |       | μA    |
| At Rated DC Blocking Voltage @ T <sub>A</sub> = 100 °C                              |                                   | 0.5         |       |       |       |       |       |       | mA    |
| Maximum Thermal Resistance, Junction to Ambient (Note 1)                            | R <sub>θJA</sub>                  | 40          |       |       |       |       |       |       | °C/W  |
| Operating and Storage Temperature Range   | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 |       |       |       |       |       |       | °C    |

NOTES: (1) Thermal resistance from junction to ambient with bridge mounted on PC Board with 0.5x0.5 in copper pads



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## RATING & CHARACTERISTIC CURVES FOR SERIES DI100 - DI110

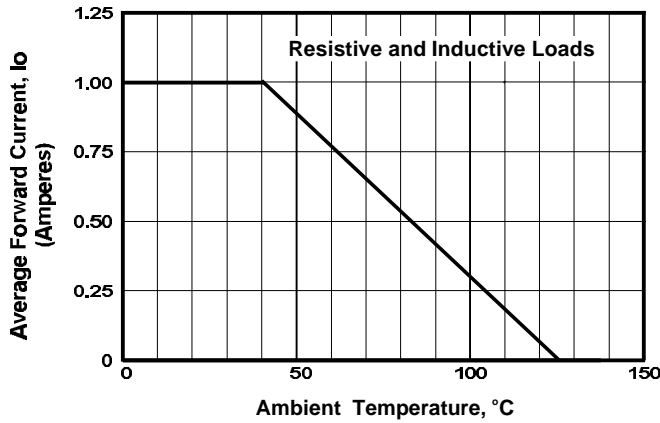


FIGURE 1. FORWARD CURRENT DERATING CURVE

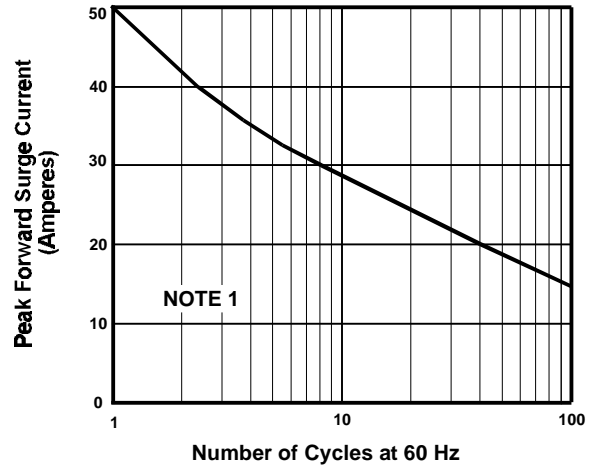


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

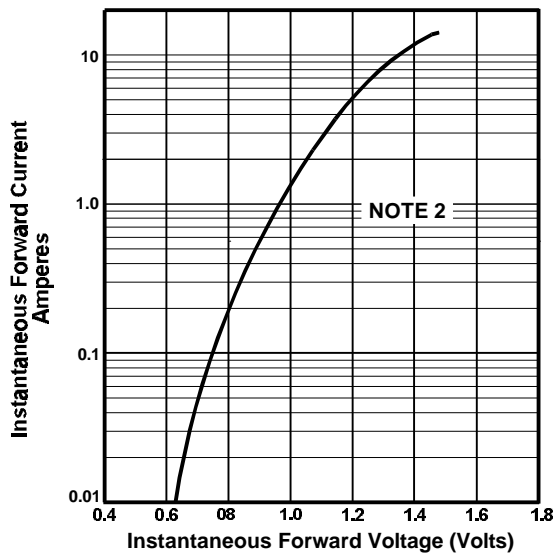


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE

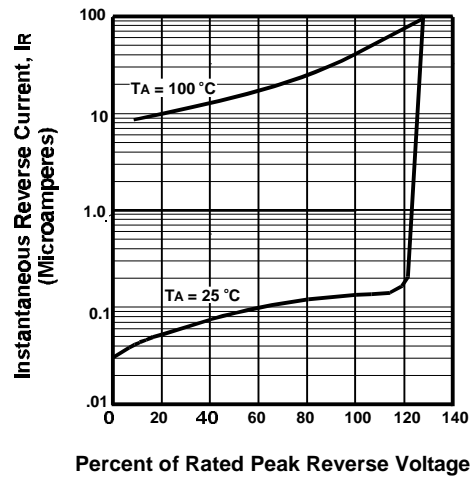


FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

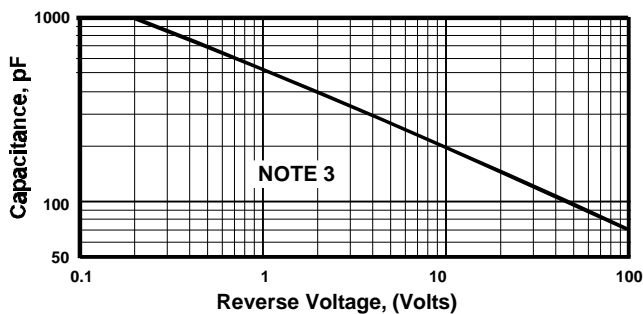


FIGURE 5. TYPICAL JUNCTION CAPACITANCE PER DIODE

**NOTES**

- (1) JEDEC Method, 8.3 mSec. Single Half Sine Wave;  $T_J = 150^\circ\text{C}$
- (2)  $T_J = 25^\circ\text{C}$ ; Pulse Width = 300  $\mu\text{Sec}$ , 1% Duty Cycle
- (3)  $T_J = 25^\circ\text{C}$ ;  $f = 1\text{ MHz}$